MOSFETs Silicon N-channel MOS (U-MOSIX-H)

# TPH1R104PB

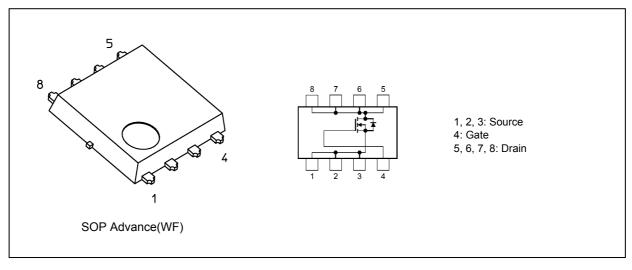
### 1. Applications

- Automotive
- Motor Drivers
- Switching Voltage Regulators

## 2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance:  $R_{\rm DS(ON)}$  = 0.95 mO (typ.) (V\_{\rm GS} = 10 V)
- (4) Low leakage current:  $I_{DSS}$  = 10  $\mu$ A (max) ( $V_{DS}$  = 40 V)
- (5) Enhancement mode:  $V_{th}$  = 2.0 to 3.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 0.5 mA)

## 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25$ °C unless otherwise specified)

Characteri	Symbol	Rating	Unit		
Drain-source voltage			V <sub>DSS</sub>	40	V
Gate-source voltage			V <sub>GSS</sub>	±20	
Drain current (DC)		(Note 1)	Ι <sub>D</sub>	120	А
Drain current (pulsed)		(Note 1)	I <sub>DP</sub>	360	1
Power dissipation	(T <sub>c</sub> = 25 °C)		PD	132	w
Power dissipation	(t = 10 s)	(Note 2)	] [	3.0	1
Power dissipation	(t = 10 s)	(Note 3)	] [	0.96	1
Single-pulse avalanche energy		(Note 4)	E <sub>AS</sub>	140	mJ
Single-pulse avalanche current			I <sub>AS</sub>	120	A
Channel temperature		(Note 5)	T <sub>ch</sub>	175	°C
Storage temperature		(Note 5)	T <sub>stg</sub>	-55 to 175	1

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

Characteristics			Symbol	Max	Unit
Channel-to-case thermal impedance	(T <sub>c</sub> = 25 °C)		Z <sub>th(ch-c)</sub>	1.13	°C/W
Channel-to-ambient thermal impedance	(t = 10 s)	(Note 2)	Z <sub>th(ch-a)</sub>	50	
Channel-to-ambient thermal impedance	(t = 10 s)	(Note 3)	Z <sub>th(ch-a)</sub>	156	

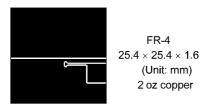
Note 1: Ensure that the channel temperature does not exceed 175 °C.

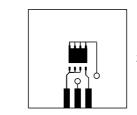
Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V<sub>DD</sub> = 32 V, T<sub>ch</sub> = 25 °C (initial), L = 7.47  $\mu$ H, R<sub>G</sub> = 25  $\Omega$ , I<sub>AS</sub> = 120 A

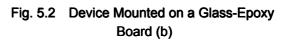
Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.





FR-4 25.4 × 25.4 × 1.6 (Unit: mm) 2 oz copper

Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)



Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

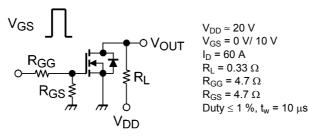
### 6. Electrical Characteristics

### 6.1. Static Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V		_	±1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V			10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	40	—	—	V
	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	20	_	_	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 mA	2.0	_	3.0	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 6 V, I <sub>D</sub> = 60 A		1.30	1.96	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 60 A		0.95	1.14	

## 6.2. Dynamic Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 300 kHz	_	4560	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	]	_	320	_	
Output capacitance	C <sub>oss</sub>	]		2940	_	
Gate resistance	r <sub>g</sub>	]	_	2.9	_	Ω
Switching time (rise time)	tr	See Fig. 6.2.1	_	8	_	ns
Switching time (turn-on time)	t <sub>on</sub>	]		22	_	
Switching time (fall time)	t <sub>f</sub>	]		23	_	
Switching time (turn-off time)	t <sub>off</sub>	]		71	_	



#### Fig. 6.2.1 Switching Time Test Circuit

### 6.3. Gate Charge Characteristics ( $T_a = 25$ °C unless otherwise specified)

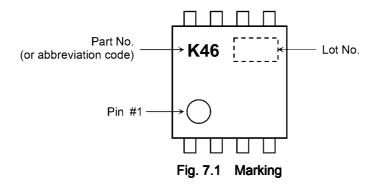
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 32 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 120 \text{ A}$		55	_	nC
Gate-source charge 1	Q <sub>gs1</sub>		_	20		
Gate-drain charge	Q <sub>gd</sub>		_	13	_	

### 6.4. Source-Drain Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

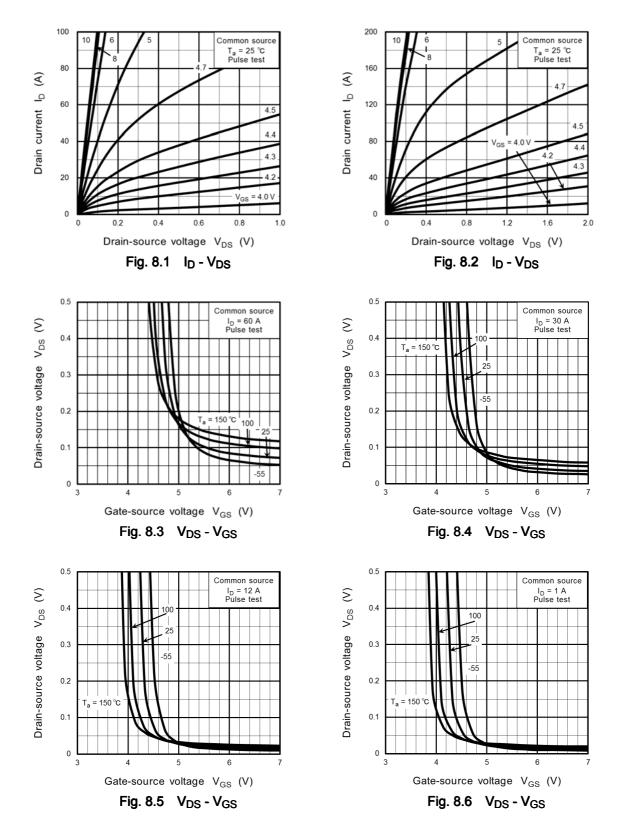
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed)	(Note 6)	I <sub>DRP</sub>	—	_	—	360	А
Diode forward voltage		V <sub>DSF</sub>	I <sub>DR</sub> = 120 A, V <sub>GS</sub> = 0 V			-1.2	V

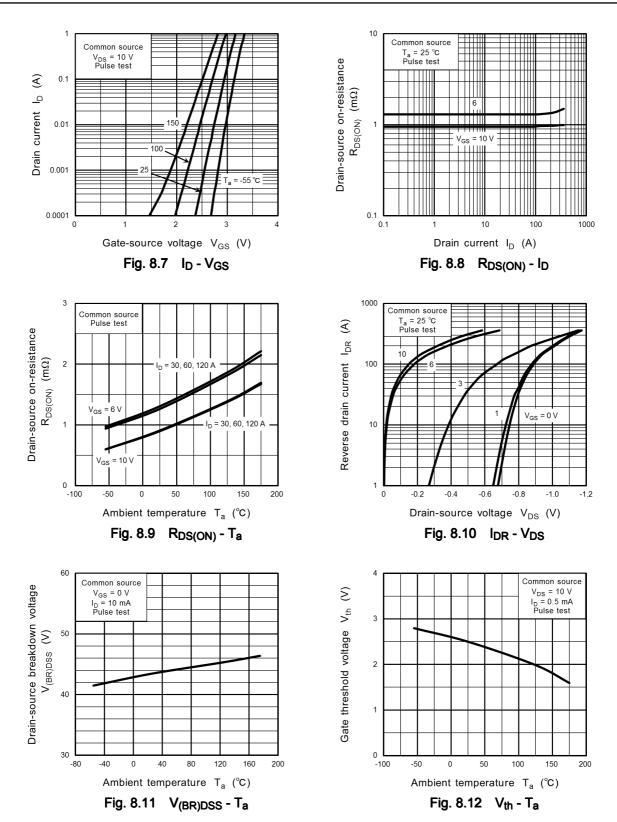
Note 6: Ensure that the channel temperature does not exceed 175 °C.

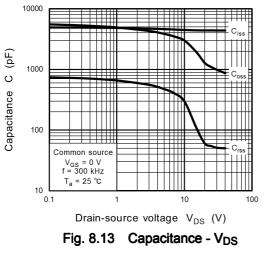
## 7. Marking



## 8. Characteristics Curves (Note)







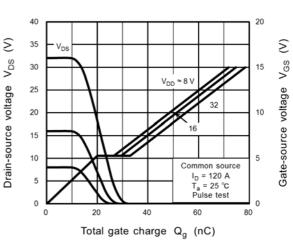


Fig. 8.14 Dynamic Input/Output Characteristics

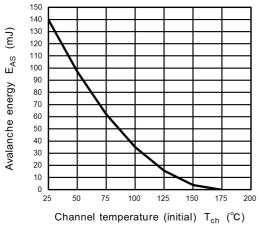


Fig. 8.15 E<sub>AS</sub> - T<sub>ch</sub>(Guaranteed Maximum)

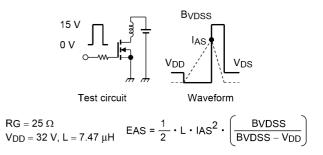
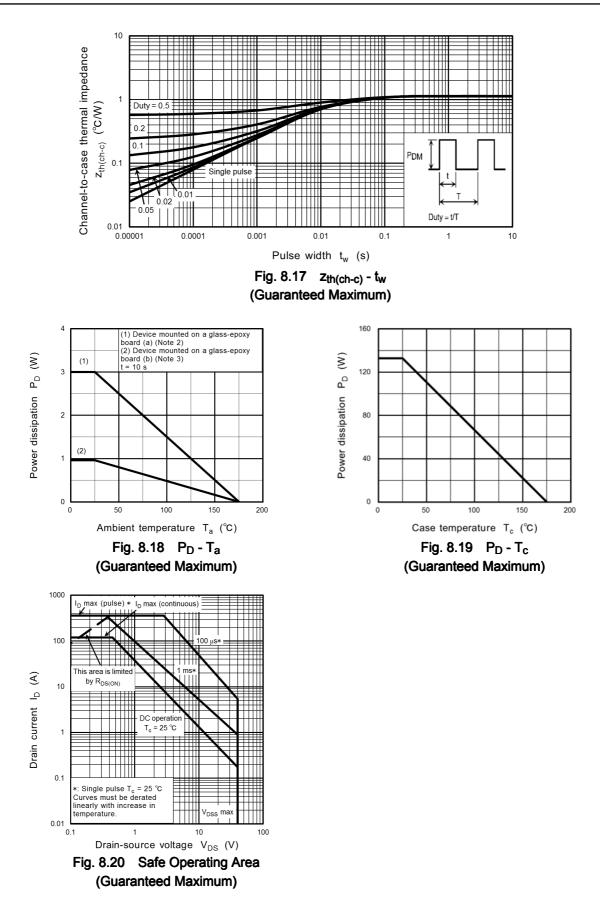


Fig. 8.16 Test Circuit/Waveform

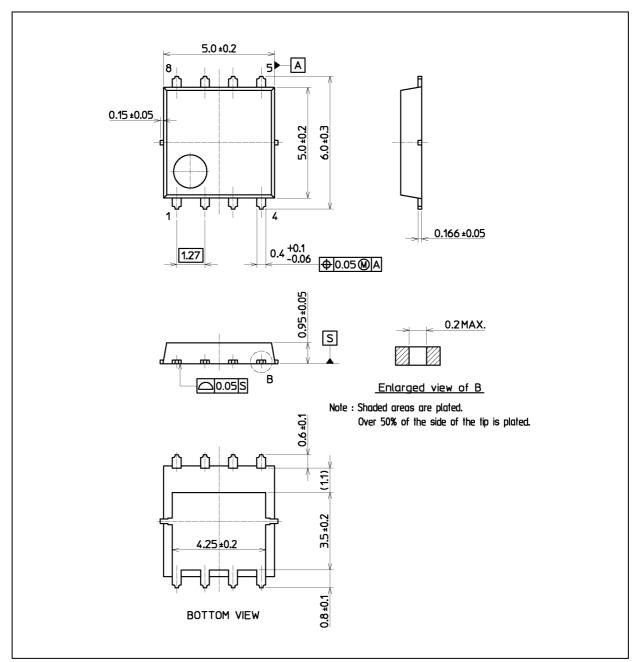


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## TPH1R104PB

### **Package Dimensions**

Unit: mm



#### Weight: 0.069 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q4A
Nickname: SOP Advance(WF)

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